

BSP129E6327

Request a Quote

BSP129E6327 Information

	Part Number	BSP129E6327
	Manufacturer	Infineon Technologies
	Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single
	Description	MOSFET N-CH 240V 350MA SOT223
280	Package	TO-261-4, TO-261AA
6		For the pricing/inventory/lead time, please contact
For Reference Only		Website: https://www.heisener.com E-mail: salesdept@heisener.com

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



BSP129E6327 Specifications

Manufacturer Part Number	BSP129E6327
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-261-4, TO-261AA
Series	SIPMOS?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	240V
Current - Continuous Drain (Id) @ 25°C	350mA (Ta)
Drive Voltage (Max Rds On, Min Rds On)	0V, 10V
Vgs(th) (Max) @ Id	1V @ 108µA
Gate Charge (Qg) (Max) @ Vgs	5.7nC @ 5V
Input Capacitance (Ciss) (Max) @ Vds	108pF @ 25V
Vgs (Max)	$\pm 20 V$
FET Feature	Depletion Mode
Power Dissipation (Max)	1.8W (Ta)
Rds On (Max) @ Id, Vgs	6 Ohm @ 350mA, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	PG-SOT223-4
Package / Case	TO-261-4, TO-261AA
	Report errors?

BSP129E6327 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

BSP129E6327 Payment Methods



BSP129E6327 Shipping Methods



If you have any question about BSP129E6327, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com